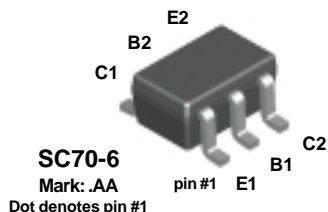
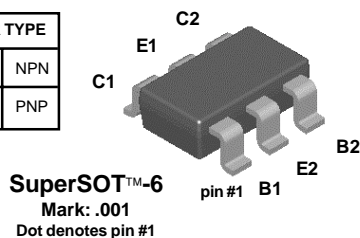


FFB2227A



| TRANSISTOR TYPE | | | |
|-----------------|----|----|-----|
| C1 | B1 | E1 | NPN |
| C2 | B2 | E2 | PNP |

FMB2227A



NPN & PNP General Purpose Amplifier

This complementary device is for use as a medium power amplifier and switch requiring collector currents up to 500 mA. Sourced from Process 19 and 63. See FFB2222A (NPN) and FFB2907A (PNP) for characteristics.

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|----------------|--|-------------|------------------|
| V_{CEO} | Collector-Emitter Voltage | 30 | V |
| V_{CBO} | Collector-Base Voltage | 60 | V |
| V_{EBO} | Emitter-Base Voltage | 5.0 | V |
| I_C | Collector Current - Continuous | 500 | mA |
| T_J, T_{stg} | Operating and Storage Junction Temperature Range | -55 to +150 | $^\circ\text{C}$ |

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
- 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

Thermal Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Characteristic | Max | | Units |
|-----------------|---|----------|----------|---------------------------|
| | | FFB2227A | FMB2227A | |
| P_D | Total Device Dissipation | 300 | 700 | mW |
| | Derate above 25°C | 2.4 | 5.6 | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 415 | 180 | $^\circ\text{C}/\text{W}$ |

NPN & PNP General Purpose Amplifier

(continued)

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Units |
|--------|-----------|-----------------|-----|-----|-----|-------|
|--------|-----------|-----------------|-----|-----|-----|-------|

OFF CHARACTERISTICS

| | | | | | | |
|---------------|--------------------------------------|----------------------------------|-----|--|----|----|
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage* | $I_C = 10\text{ mA}, I_B = 0$ | 30 | | | V |
| $V_{(BR)CBO}$ | Collector-Base Breakdown Voltage | $I_C = 10\ \mu\text{A}, I_E = 0$ | 60 | | | V |
| $V_{(BR)EBO}$ | Emitter-Base Breakdown Voltage | $I_E = 10\ \mu\text{A}, I_C = 0$ | 5.0 | | | V |
| I_{CBO} | Collector Cutoff Current | $V_{CB} = 50\text{ V}, I_E = 0$ | | | 30 | nA |
| I_{EBO} | Emitter Cutoff Current | $V_{EB} = 3.0\text{ V}, I_C = 0$ | | | 30 | nA |

ON CHARACTERISTICS

| | | | | | | |
|---------------|---------------------------------------|---|-----------------------|--|------------|--------|
| h_{FE} | DC Current Gain | $I_C = 1.0\text{ mA}, V_{CE} = 10\text{ V}$ $I_C = 10\text{ mA}, V_{CE} = 10\text{ V}$ $I_C = 150\text{ mA}, V_{CE} = 10\text{ V}^*$ $I_C = 300\text{ mA}, V_{CE} = 10\text{ V}^*$ | 50 75 100 30 | | | |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage* | $I_C = 150\text{ mA}, I_B = 15\text{ mA}$ $I_C = 300\text{ mA}, I_B = 30\text{ mA}$ | | | 0.4 1.4 | V V |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage* | $I_C = 150\text{ mA}, I_B = 15\text{ mA}$ | | | 1.3 | V |

SMALL SIGNAL CHARACTERISTICS

| | | | | | | |
|-----------|----------------------------------|---|--|-----|--|-----|
| f_T | Current Gain - Bandwidth Product | $I_C = 50\text{ mA}, V_{CE} = 20\text{ V},$ $f = 100\text{ MHz}$ | | 250 | | MHz |
| C_{obo} | Output Capacitance | $V_{CB} = 10\text{ V}, I_E = 0, f = 100\text{ kHz}$ | | 4.0 | | pF |
| C_{ibo} | Input Capacitance | $V_{EB} = 2.0\text{ V}, I_C = 0, f = 100\text{ kHz}$ | | 12 | | pF |
| NF | Noise Figure | $I_C = 100\ \mu\text{A}, V_{CE} = 10\text{ V},$ $R_S = 1.0\text{ k}\Omega, f = 1.0\text{ kHz}$ | | 2.0 | | dB |

SWITCHING CHARACTERISTICS

| | | | | | | |
|-----------|---------------|--|--|-----|--|----|
| t_{on} | Turn-on Time | $V_{CC} = 30\text{ V}, I_C = 150\text{ mA},$ $I_{B1} = 15\text{ mA}$ | | 30 | | ns |
| t_d | Delay Time | | | 8.0 | | ns |
| t_r | Rise Time | | | 20 | | ns |
| t_{off} | Turn-off Time | $V_{CC} = 6.0\text{ V}, I_C = 150\text{ mA}$ $I_{B1} = I_{B2} = 15\text{ mA}$ | | 80 | | ns |
| t_s | Storage Time | | | 60 | | ns |
| t_f | Fall Time | | | 20 | | ns |

*Pulse Test: Pulse Width $\leq 300\ \mu\text{s}$, Duty Cycle $\leq 2.0\%$

NOTE: All voltages (V) and currents (A) are negative polarity for PNP transistors.

FFB2227A / FMB2227A

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| FACT™ | OPTOPLANAR™ | SuperSOT™-3 | |
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PRODUCT STATUS DEFINITIONS

Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|------------------------|---|
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| Preliminary | First Production | This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |
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Rev. G